

L Number	Hits	Search Text	DB	Time stamp
37	8	(("6225162") or ("6388305") or ("6168987") or ("6133602") or ("5591681") or ("5436481") or ("6133093") or ("6096604")).PN.	USPAT	2003/04/18 13:51
48	9	((("6225162") or ("6388305") or ("6168987") or ("6133602") or ("5591681") or ("5436481") or ("6133093") or ("6096604") or ("5572050")).PN.	USPAT	2003/04/18 13:51
-	3	((("6004847") or ("5104819") or ("6274428")).PN.	USPAT	2003/04/18 13:37
-	524	(438/255).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/01 10:08
-	479	(438/258).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/01 10:10
-	271	(438/261).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/01 10:10
-	1104	(438/257).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/01 10:10
-	450	(438/756).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/01 10:11
-	116	(438/757).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/01 10:11
-	308	(438/724).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/01 10:11
-	3039	438/255,258,201,261,257,756,757,724.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/01 10:15
-	14	438/255,258,201,261,257,756,757,724.ccls. and (ONS or (oxide adj nitride adj silicon))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/01 10:17
-	1	438/255,258,201,261,257,756,757,724.ccls. and ((ONS or (oxide adj nitride adj silicon)) same (ONO or (oxide adj nitride adj oxide)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/01 10:18
-	24	(ONS or (oxide adj nitride adj silicon)) same (ONO or (oxide adj nitride adj oxide))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/01 10:21
-	13	((ONS or (oxide adj nitride adj silicon)) same (ONO or (oxide adj nitride adj oxide))) and semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/04 10:07

		8	((("6004847") or ("5104819") or ("6274428") or ("6180457") or ("6429470") or ("6318267") or ("5572050") or ("4775549")).PN.	USPAT	2003/04/07 12:58
		20	((ONS or (oxide adj nitride adj silicon)) same (ONO or (oxide adj nitride adj oxide))) and (photoresist or mask)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/04 10:09
		10	((((ONS or (oxide adj nitride adj silicon)) same (ONO or (oxide adj nitride adj oxide))) and (photoresist or mask)) and semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/04 10:10
		191	(438/201).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/04 11:17
		0	((ONO or (oxide adj nitride adj oxide)) same (ONS or (oxide adj nitride adj silicon)) same (photoresist or mask)) and (re-oxidiz\$6 or (second adj oxidiz\$6))	USPAT; JPO	2003/04/07 12:34
		0	((ONO or (oxide adj nitride adj oxide)) same (ONS or (oxide adj nitride adj silicon)) and (photoresist or mask) and (re-oxidiz\$6 or (second adj oxidiz\$6))	USPAT; JPO	2003/04/07 12:38
		0	(ONO or (oxide adj nitride adj oxide)) and (ONS or (oxide adj nitride adj silicon)) and (photoresist or mask) and (re-oxidiz\$6 or (second adj oxidiz\$6)) and semiconductor	USPAT; JPO	2003/04/07 12:38
		66	(ONO or (oxide adj nitride adj oxide)) and (ONS or (oxide adj nitride adj silicon))	USPAT; JPO	2003/04/07 12:38
	80283		(ONO or (oxide adj nitride adj oxide)) or (ONS or (oxide adj nitride adj silicon))	USPAT; JPO	2003/04/07 12:38
		23	(ONO or (oxide adj nitride adj oxide)) same (ONS or (oxide adj nitride adj silicon))	USPAT; JPO	2003/04/07 12:38
		0	((ONO or (oxide adj nitride adj oxide)) and (ONS or (oxide adj nitride adj silicon)) ) and (photoresist or mask) and (re-oxidiz\$6 or (second adj oxidiz\$6))	USPAT; JPO	2003/04/07 12:39
		0	((ONO or (oxide adj nitride adj oxide)) same (ONS or (oxide adj nitride adj silicon)) ) and (photoresist or mask) and (re-oxidiz\$6 or (second adj oxidiz\$6))	USPAT; JPO	2003/04/07 12:41
		11	((ONO or (oxide adj nitride adj oxide)) same (ONS or (oxide adj nitride adj silicon)) ) and (photoresist or mask) and semiconductor	USPAT; JPO	2003/04/07 12:40
		22	((ONO or (oxide adj nitride adj oxide)) and (ONS or (oxide adj nitride adj silicon)) ) and (photoresist or mask) and semiconductor	USPAT; JPO	2003/04/07 12:40
		36	((ONO or (oxide adj nitride adj oxide)) or (ONS or (oxide adj nitride adj silicon)) ) and (photoresist or mask) and (re-oxidiz\$6 or (second adj oxidiz\$6))	USPAT; JPO	2003/04/07 12:40
		0	((ONO or (oxide adj nitride adj oxide)) same (ONS or (oxide adj nitride adj silicon)) ) and (photoresist or mask) and (second adj oxidiz\$6)	USPAT; JPO	2003/04/07 12:41
		0	((ONO or (oxide adj nitride adj oxide)) and (ONS or (oxide adj nitride adj silicon)) ) and (photoresist or mask) and (second adj oxidiz\$6)	USPAT; JPO	2003/04/07 12:41
		10	((("5756376") or ("5770467") or ("6318267") or ("6004847") or ("6429470") or ("6180457") or ("5104819") or ("5572050") or ("6472259") or ("4775549"))).PN.	USPAT	2003/04/08 09:24

-	1	("5650344").PN.	USPAT	2003/04/08 09:37
-	5	(("5650344") or ("4698787") or ("4543597") or ("5049514") or ("5083172")).PN.	USPAT	2003/04/08 09:38